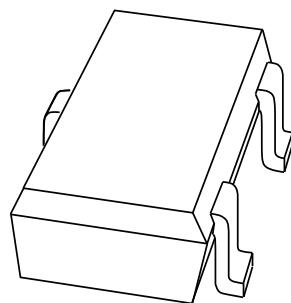


DATA SHEET



BAP63-05W Silicon PIN diode

Product specification
Supersedes data of 2001 Apr 04

2001 May 18



Silicon PIN diode**BAP63-05W****FEATURES**

- High speed switching for RF signals
- Low diode capacitance
- Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz.

APPLICATIONS

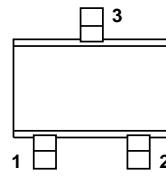
- RF attenuators and switches.

DESCRIPTION

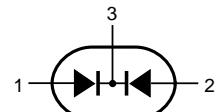
Two planar PIN diodes in common cathode configuration in a SOT323 small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	anode (a1)
2	anode (a2)
3	common cathode



Top view



MAM382

Marking code: W9-.

Fig.1 Simplified outline (SOT323) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage		–	50	V
I_F	continuous forward current		–	100	mA
P_{tot}	total power dissipation	$T_s \leq 90^\circ\text{C}$	–	240	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–65	+150	°C

Silicon PIN diode

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ELECTRICAL CHARACTERISTICS

 $T_j = 25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					
V_F	forward voltage	$I_F = 50 \text{ mA}$	0.95	1.1	V
I_R	reverse current	$V_R = 35 \text{ V}$	–	10	nA
C_d	diode capacitance	$V_R = 0; f = 1 \text{ MHz}$	0.4	–	pF
		$V_R = 1 \text{ V}; f = 1 \text{ MHz}$	0.35	–	pF
		$V_R = 20 \text{ V}; f = 1 \text{ MHz}$	0.3	0.35	pF
r_D	diode forward resistance	$I_F = 0.5 \text{ mA}; f = 100 \text{ MHz}; \text{note 1}$	2.5	3.5	Ω
		$I_F = 1 \text{ mA}; f = 100 \text{ MHz}; \text{note 1}$	1.95	3	Ω
		$I_F = 10 \text{ mA}; f = 100 \text{ MHz}; \text{note 1}$	1.17	1.8	Ω
		$I_F = 100 \text{ mA}; f = 100 \text{ MHz}; \text{note 1}$	0.9	1.5	Ω
$ s_{21} ^2$	isolation	$V_R = 0; f = 900 \text{ MHz}$	14.5	–	dB
		$V_R = 0; f = 1800 \text{ MHz}$	9.5	–	dB
		$V_R = 0; f = 2450 \text{ MHz}$	7.0	–	dB
$ s_{21} ^2$	insertion loss	$I_F = 0.5 \text{ mA}; f = 900 \text{ MHz}$	0.23	–	dB
		$I_F = 0.5 \text{ mA}; f = 1800 \text{ MHz}$	0.27	–	dB
		$I_F = 0.5 \text{ mA}; f = 2450 \text{ MHz}$	0.33	–	dB
$ s_{21} ^2$	insertion loss	$I_F = 1 \text{ mA}; f = 900 \text{ MHz}$	0.19	–	dB
		$I_F = 1 \text{ mA}; f = 1800 \text{ MHz}$	0.24	–	dB
		$I_F = 1 \text{ mA}; f = 2450 \text{ MHz}$	0.30	–	dB
$ s_{21} ^2$	insertion loss	$I_F = 10 \text{ mA}; f = 900 \text{ MHz}$	0.14	–	dB
		$I_F = 10 \text{ mA}; f = 1800 \text{ MHz}$	0.19	–	dB
		$I_F = 10 \text{ mA}; f = 2450 \text{ MHz}$	0.25	–	dB
$ s_{21} ^2$	insertion loss	$I_F = 100 \text{ mA}; f = 900 \text{ MHz}$	0.11	–	dB
		$I_F = 100 \text{ mA}; f = 1800 \text{ MHz}$	0.17	–	dB
		$I_F = 100 \text{ mA}; f = 2450 \text{ MHz}$	0.23	–	dB
τ_L	charge carrier life time	when switched from $I_F = 10 \text{ mA}$ to $I_R = 6 \text{ mA}; R_L = 100 \Omega$; measured at $I_R = 3 \text{ mA}$	310	–	ns
L_S	series inductance	$I_F = 100 \text{ mA}; f = 100 \text{ MHz}$	1.5	–	nH

Note

- Guaranteed on AQL basis: inspection level S4, AQL 1.0.

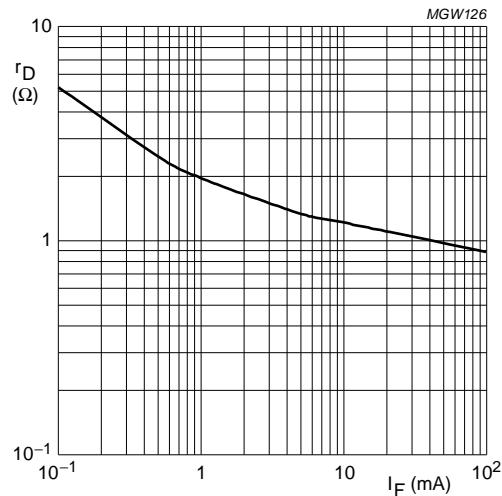
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th,j-s}$	thermal resistance from junction to soldering point	250	K/W

Silicon PIN diode

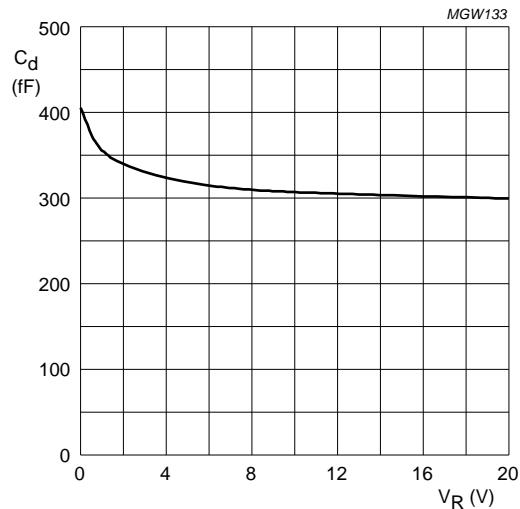
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GRAPHICAL DATA



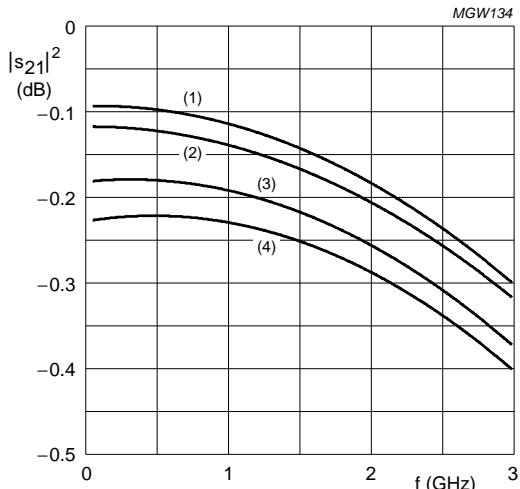
$f = 100$ MHz; $T_j = 25$ °C.

Fig.2 Forward resistance as a function of forward current; typical values.



$f = 1$ MHz; $T_j = 25$ °C.

Fig.3 Diode capacitance as a function of reverse voltage; typical values.

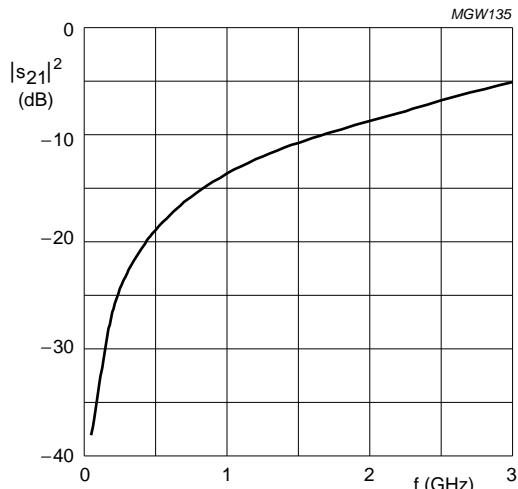


(1) $I_F = 100$ mA. (3) $I_F = 1$ mA.
 (2) $I_F = 10$ mA. (4) $I_F = 0.5$ mA.

Diode inserted in series with a 50Ω stripline circuit and biased via the analyzer Tee network.

$T_{amb} = 25$ °C.

Fig.4 Insertion loss ($|s_{21}|^2$) of the diode in on-state as a function of frequency; typical values.



Diode zero biased and inserted in series with a 50Ω stripline circuit.

$T_{amb} = 25$ °C.

Fig.5 Isolation ($|s_{21}|^2$) of the diode in off-state as a function of frequency; typical values.

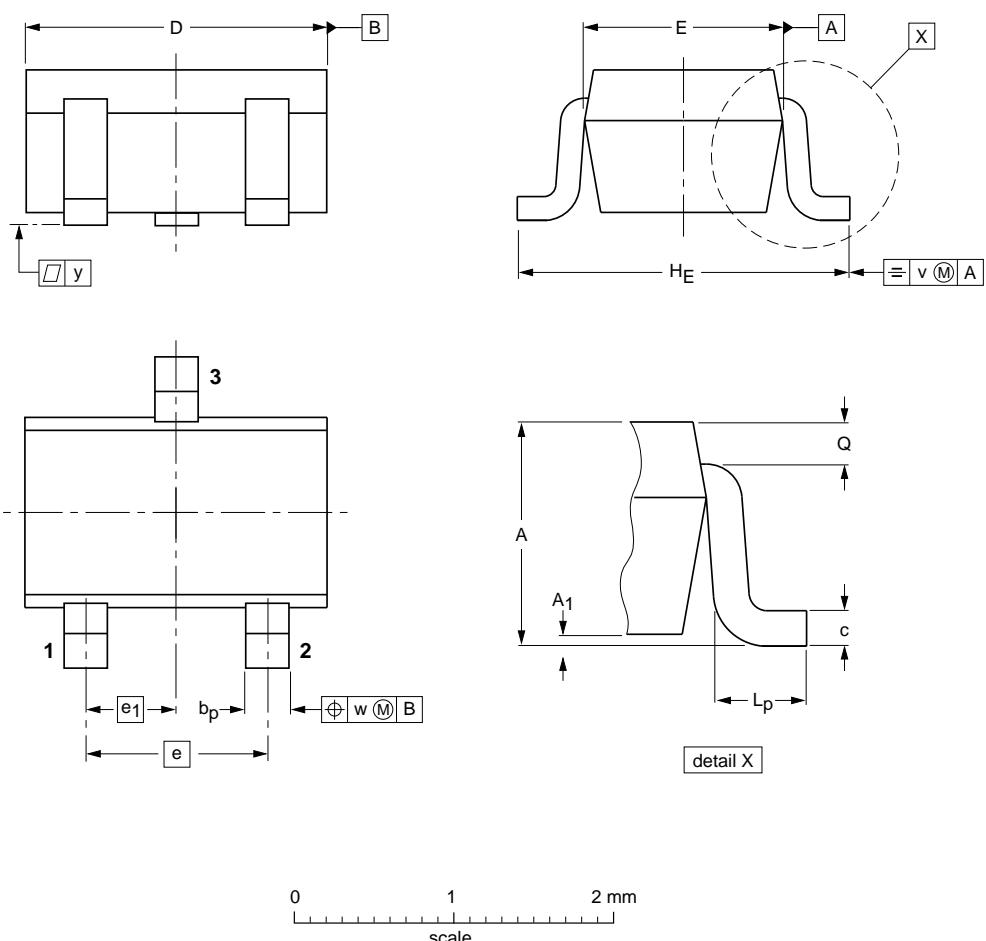
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PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA	SC-70		
SOT323						-04-11-04- 06-03-16

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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